

## 5V, 3.1A, 550KHz High Efficiency Low Ripple Synchronous Step-Up Converter

### Description

The FP6717 is a high efficiency, fixed frequency 550KHz, current mode PWM boost DC/DC converter which could operate battery such as input voltage down to 2.5V. The converter output voltage can be adjusted to a maximum of 5.25V by an external resistor divider. Besides the converter includes a 39mΩ N-channel MOSFET switch and 42mΩP-channel synchronous rectifier. So no external Schottky diode is required and could get better efficiency near 90%.

The converter is based on a fixed frequency, current mode, pulse-width-modulation PWM controller that goes automatically into PSM mode at light load.

When converter operation into discontinuous mode, the internal anti-ringing switch will reduce interference and radiated electromagnetic energy.

The FP6717 is available in a space-saving SOP-8 (Exposed Pad) package for portable application.

### Features

- High Efficiency up to 90%
- Low  $R_{DS(ON)}$  Integrated Power MOSFET
- NMOS 39mΩ/PMOS 42mΩ
- Wide Input Voltage Range: 2.5V to 5.25V
- Fixed 550KHz Switching Frequency
- Low-Power Mode for Light Load Conditions
- $\pm 2.0\%$  Voltage Reference Accuracy
- Adjustable Current Limit
- PMOS Current Limit for Short Circuit Protection
- Low Quiescent Current
- Input Under Voltage Lockout
- Internal Compensation Function
- Built-In Soft Start Function
- Over-Temperature Protection with Auto Recovery
- Output Overvoltage Protection
- SOP-8 (Exposed Pad) Pb-Free Package

### Applications

- Portable Power Bank
- Wireless Equipment
- Handheld Instrument
- GPS Receiver

### Pin Assignments

SP Package (SOP-8 Exposed Pad)

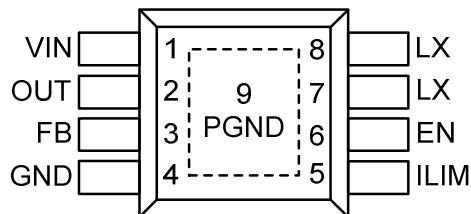
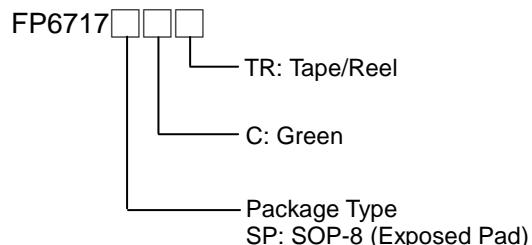
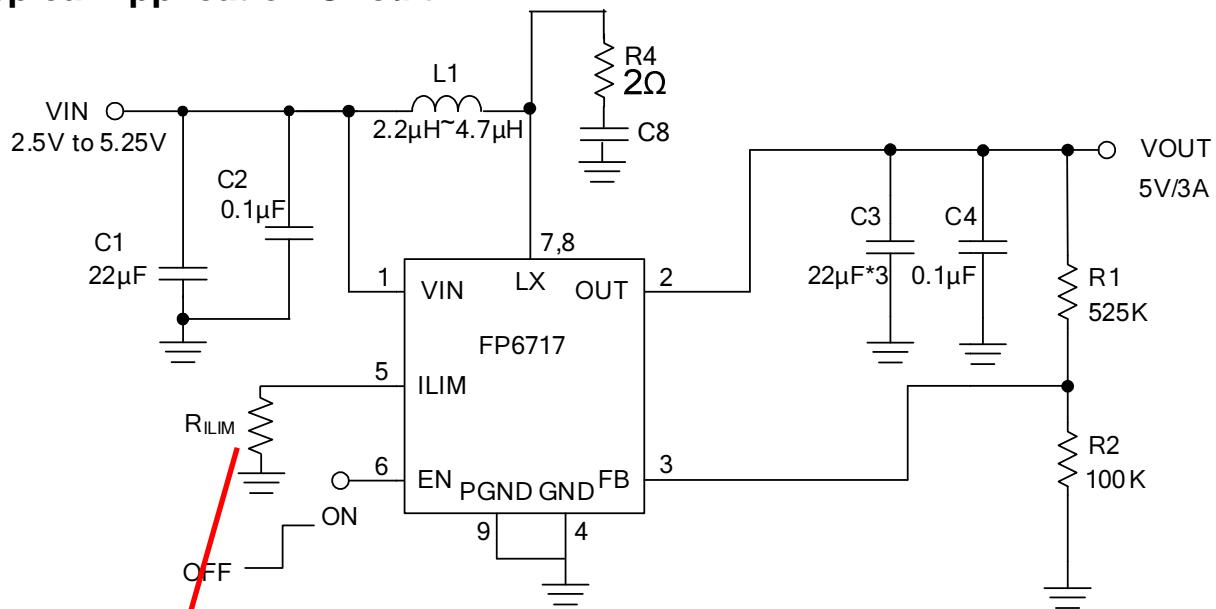


Figure 1. Pin Assignment of FP6717

### Ordering Information



## Typical Application Circuit



注意：IC第5脚是限流脚，限制的是输入端的电流。

输出电流2A时，建议阻值：1M

Figure 2. Typical Application Circuit

ILIM Resistance Value (MΩ)	Typical Input Limits (A)	Average Input Current vs R <sub>PROG</sub>																								
0.5	8	<p>The graph plots Average Input Current (A) on the y-axis (0 to 9) against R<sub>PROG</sub> (MΩ) on the x-axis (0 to 10). The curve starts at approximately (0.5, 8) and decreases rapidly, leveling off near zero current as R<sub>PROG</sub> increases beyond 2MΩ.</p> <table border="1"> <caption>Data points estimated from the graph</caption> <thead> <tr> <th>R<sub>PROG</sub> (MΩ)</th> <th>Average Input Current (A)</th> </tr> </thead> <tbody> <tr><td>0.5</td><td>8.0</td></tr> <tr><td>1.0</td><td>4.0</td></tr> <tr><td>2.0</td><td>1.0</td></tr> <tr><td>3.0</td><td>0.5</td></tr> <tr><td>4.0</td><td>0.3</td></tr> <tr><td>5.0</td><td>0.2</td></tr> <tr><td>6.0</td><td>0.15</td></tr> <tr><td>7.0</td><td>0.1</td></tr> <tr><td>8.0</td><td>0.08</td></tr> <tr><td>9.0</td><td>0.06</td></tr> <tr><td>10.0</td><td>0.05</td></tr> </tbody> </table>	R <sub>PROG</sub> (MΩ)	Average Input Current (A)	0.5	8.0	1.0	4.0	2.0	1.0	3.0	0.5	4.0	0.3	5.0	0.2	6.0	0.15	7.0	0.1	8.0	0.08	9.0	0.06	10.0	0.05
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1	4																									
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4	1																									
8	0.5																									

## Functional Pin Description

Pin Name	Pin No.	Pin Function
VIN	1	Power Supply Input Pin.
OUT	2	Output of the Synchronous Rectifier.
FB	3	Voltage Feedback Input Pin.
GND	4	Ground Pin. Connect GND to exposed pad.
ILIM	5	Programming Input for Average Input Current.
EN	6	Logic Controlled Shutdown Input.
LX	7,8	Power Switching Connection. Connect LX to the inductor and output rectifier.
PGND	9	Power Ground Pin.

## Block Diagram

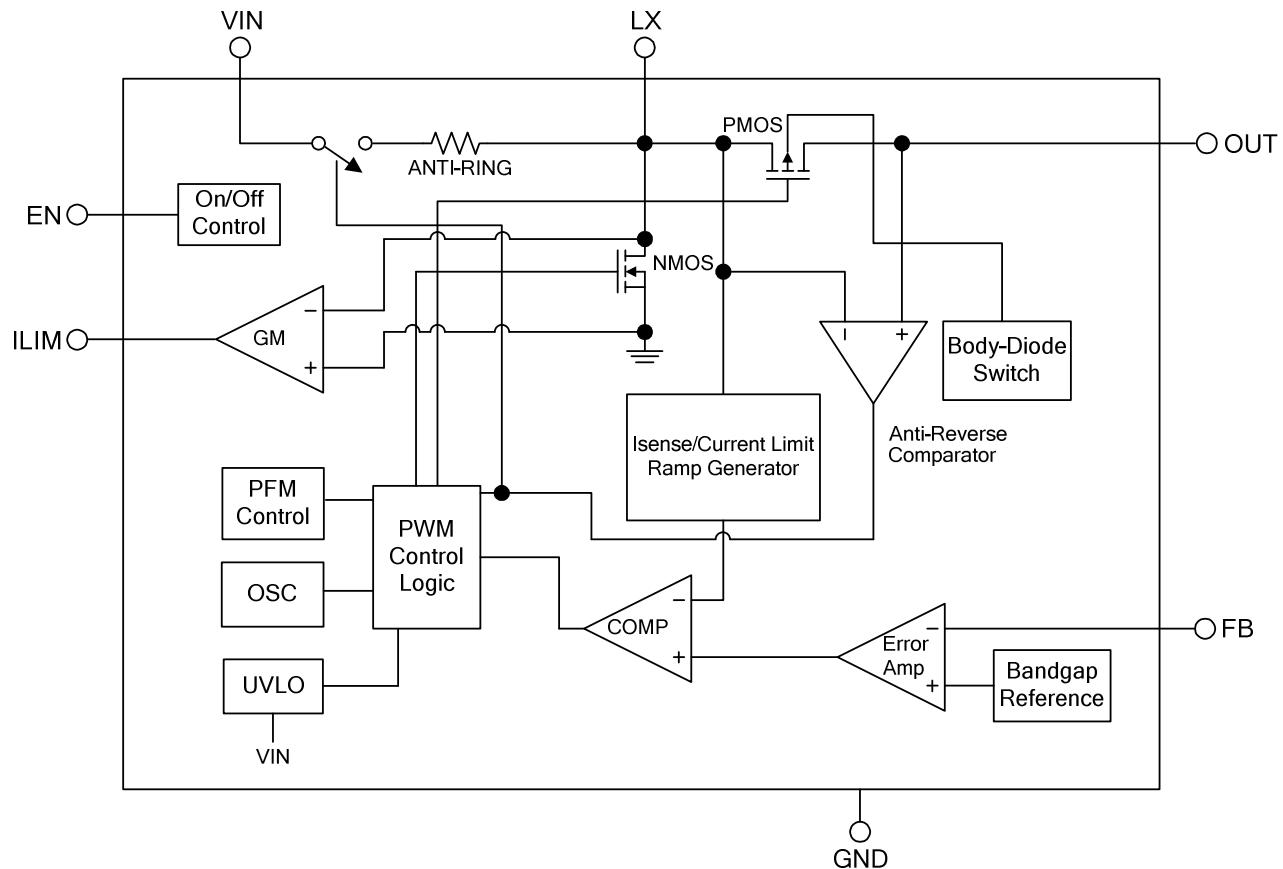


Figure 3. Block Diagram of FP6717

## Absolute Maximum Ratings (Note 1)

- Supply Voltage  $V_{IN}$  ----- -0.3V to +6.5V
- LX Voltage  $V_{LX}$  ----- -0.3V to +6.5V
- All Other Pins Voltage ----- -0.3V to +6.5V
- Maximum Junction Temperature ( $T_J$ ) ----- +150°C
- Storage Temperature ( $T_S$ ) ----- -65°C to +150°C
- Lead Temperature (Soldering, 10sec.) ----- +260°C
- Package Thermal Resistance, ( $\theta_{JA}$ )
  - SOP-8 (Exposed Pad) ----- 60°C/W
- Package Thermal Resistance, ( $\theta_{JC}$ )
  - SOP-8 (Exposed Pad) ----- 15°C/W

Note 1 : Stresses beyond this listed under "Absolute Maximum Ratings" may cause permanent damage to the device.

## Recommended Operating Conditions

- Supply Voltage  $V_{IN}$  ----- +2.5V to +5.25V
- Output Voltage Range ----- up to +5.25V
- Operation Temperature Range ----- -40°C to +85°C

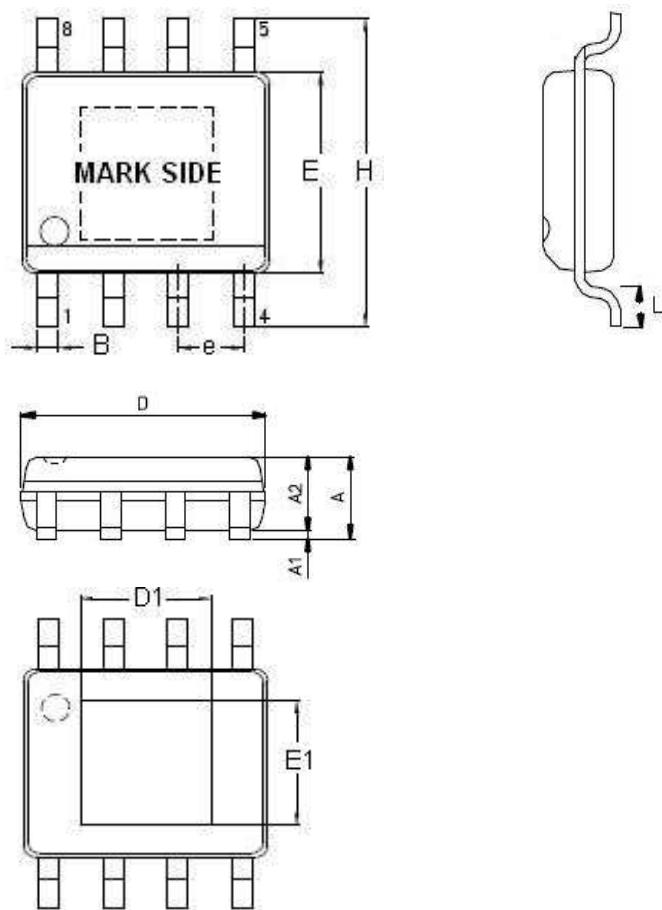
## Electrical Characteristics

( $V_{IN}=3.3V$ ,  $T_A=25^\circ C$  , unless otherwise specified.)

Parameter	Symbol	Conditions	Min	Typ	Max	Unit
VIN Input Supply Voltage	$V_{IN}$		2.5		5.25	V
VIN Supply Current (Switching)		$V_{IN}=3.3V$ , $V_{FB}=0.7V$ Measure $V_{IN}$		300	500	$\mu A$
VIN Supply Current (No switching)		$V_{FB}=1V$		45		$\mu A$
Feedback Voltage	$V_{FB}$	$2.5V \leq V_{IN} \leq 5.5V$	0.784	0.8	0.816	V
High-Side PMOSFET $R_{DS(ON)}$				42		$m\Omega$
Low-Side NMOSFET $R_{DS(ON)}$				39		$m\Omega$
High-Side MOSFET Leakage Current	$I_{LX(leak)}$	$V_{LX}=5.5V$ , $V_{OUT}=0V$			10	$\mu A$
Low-Side MOSFET Leakage Current		$V_{LX}=5.5V$			10	$\mu A$
Oscillation Frequency	$F_{osc}$		450	550	650	KHz
Short Circuit Trip Point		Monitored FB voltage		0.3		V
Short Circuit Current Limit		$V_{IN} = 3.3V$		50		mA
Maximum Duty Cycle	$D_{MAX}$	$V_{IN}=3.3V$	90			%
ILIM Current		$R_{ILIM}=500K$		8		A
ILIM Current Gain		$V_{IN}=3.3V$		8		$M\Omega\text{-A/A}$
Line Regulation		$V_{IN}=2.5V$ to $5.5V$ , $I_{OUT}=100mA$			1	%
Load Regulation		$I_{OUT}=0A$ to $1A$		0.5		%
Input UVLO Threshold	$V_{UVLO(VTH)}$	$V_{IN}$ Rising		2.3		V
Under Voltage Lockout Threshold Hysteresis	$V_{UVLO(HYS)}$	$V_{IN}$ Falling		250		mV
OVP Threshold Voltage on OUT Pin				5.7		V
OVP Threshold Hysteresis				350		mV
Internal Soft-Start Time				1	3	ms
EN Input Low Voltage	$V_{EN(L)}$				0.4	V
EN Input High Voltage	$V_{EN(H)}$		1.4			V
EN Input Current	$I_{EN}$	$V_{IN}=3.3V$		2		$\mu A$
Thermal Shutdown Threshold (Note 2)	TSD			150		$^\circ C$
Thermal Shutdown Hysteresis				30		$^\circ C$

## Outline Information

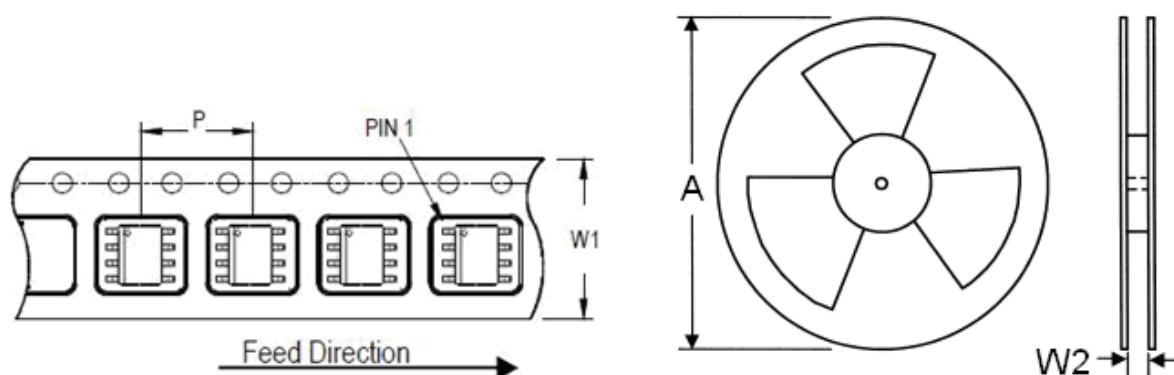
SOP-8 (Exposed Pad) Package (Unit: mm)



SYMBOLS UNIT	DIMENSION IN MILLIMETER	
	MIN	MAX
A	1.25	1.70
A1	0.00	0.15
A2	1.25	1.55
B	0.31	0.51
D	4.80	5.00
D1	3.04	3.50
E	3.80	4.00
E1	2.15	2.41
e	1.20	1.34
H	5.80	6.20
L	0.40	1.27

Note : Followed From JEDEC MO-012-E.

## Carrier Dimensions



Tape Size (W1) mm	Pocket Pitch (P) mm	Reel Size (A)		Reel Width (W2) mm	Empty Cavity Length mm	Units per Reel
		in	mm			
12	8	13	330	12.4	400~1000	2,500

### Life Support Policy

Fitipower's products are not authorized for use as critical components in life support devices or other medical systems.

# FP6717 IC特性

- 92%高效能同步升压转换器.
- 输入电压应用范围： 2.5V 至 5.25V.
- IC 在关断状态可完全隔离 输入端VIN 与输出端VOUT.
- 内置低内阻功率 MOSFET管.  
NMOS 39mΩ / PMOS 42mΩ
- 550KHz 固定操作频率.
- PWM / PSM 双套式控制, 能自动切换到PSM 套式以提升轻载状态效能.
- ±2.0% 电压精确度.
- 可调电感峰值限流点，藉由ILIM 脚位电阻值.
- 输出端短路保护机制.
- IC静态电流低.
- 快速暂态反应
- 内置软启动功能及输入欠压锁定.
- IC过温保护及自动恢复侦测

## 外部元件选择及设定

FP6716/17 反馈电压  $V_{FB}=0.8V$ ，所以输出电压计算公式 $V_{out}=0.8V * (1+R1/R2)$ , 分压电阻阻值以 10KΩ or 100KΩ 为建议级距 .

Part Number	Output Voltage (V)	R1 (KΩ)	R2 (KΩ)	Note
FP6716 FP6717	5.0	525	100	Resistor accuracy is 1%
	5.1	645	120	
	5.25	584.1	105	

最大输出电压额定建议值为5.25V。上表为输出端反馈分压电阻设定值。

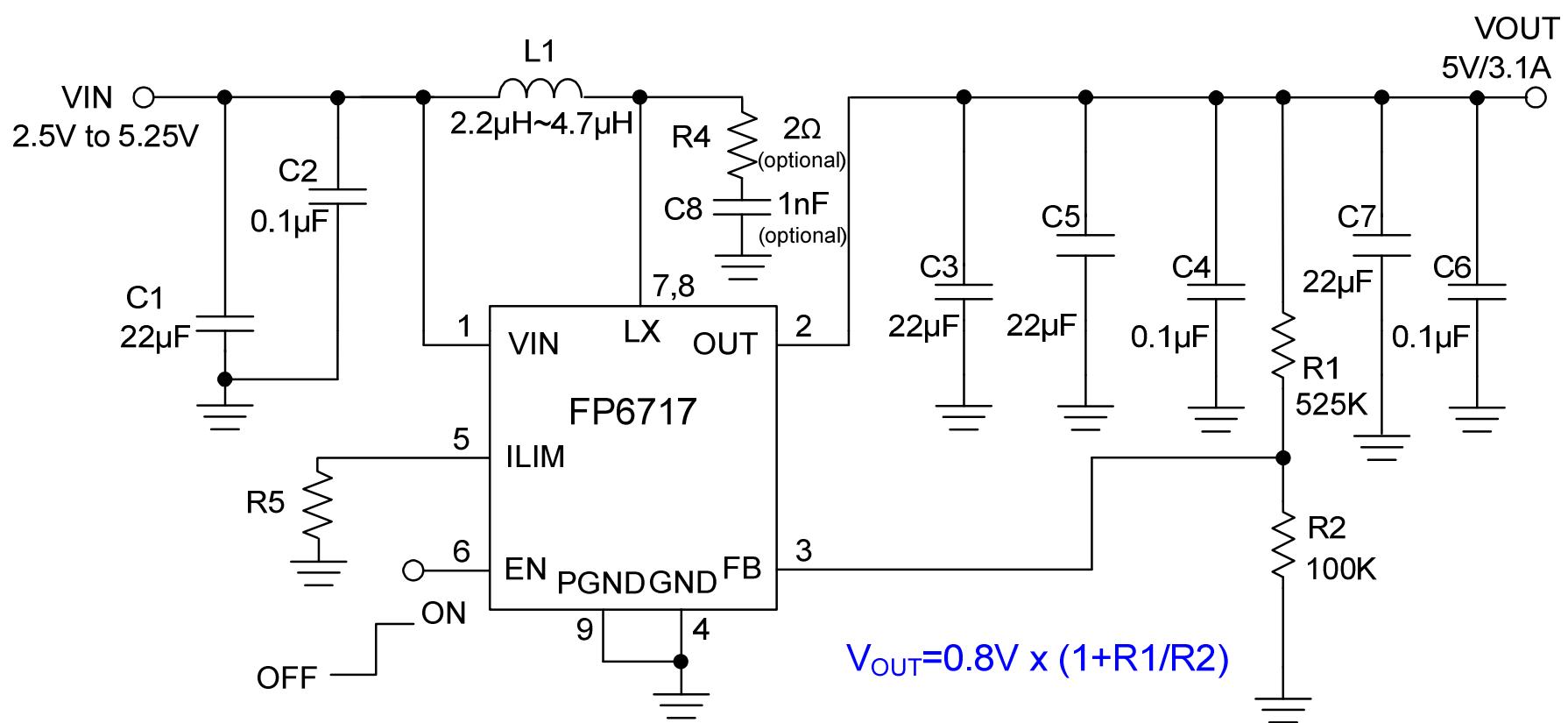
输入 / 输出电容 尺寸型式，电感电流额定会影响升压 IC 的稳定性及可靠度。

Part Number	Output Loading	C <sub>IN</sub> (uF)	C <sub>OUT</sub> (uF)	Inductor (uH)
FP6716SPCTR	5.0V/2.1A	22 (1206)	2x22(1206)	2.2~4.7 (6A current rating)

电感额定电流的计算公式为： $\{P_{OUT}/(V_{IN} * \eta)\} * 1.3$  倍。1.3倍的设定倍率是考量电感电流峰值涟波。

举例来说，  $\{(5V * 2.1A) / (3V * 0.85)\} * 1.3 = 5.35A$ , 所以使用者可挑选6A 额定电流的电感。.

# FP6717典型应用电路

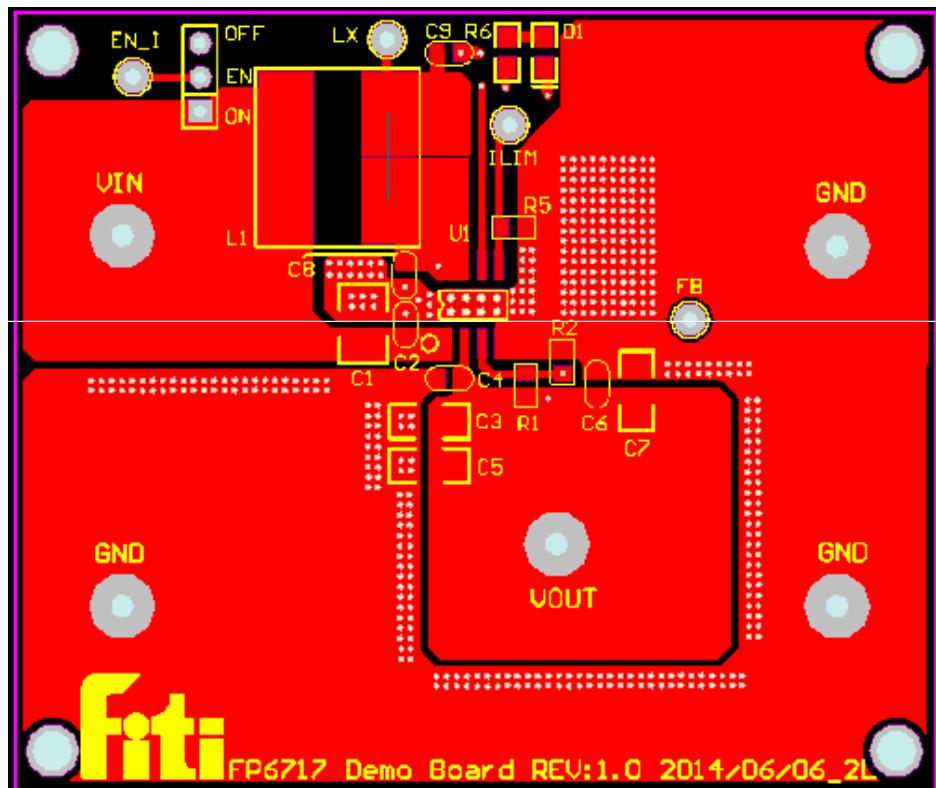


BOM 表:

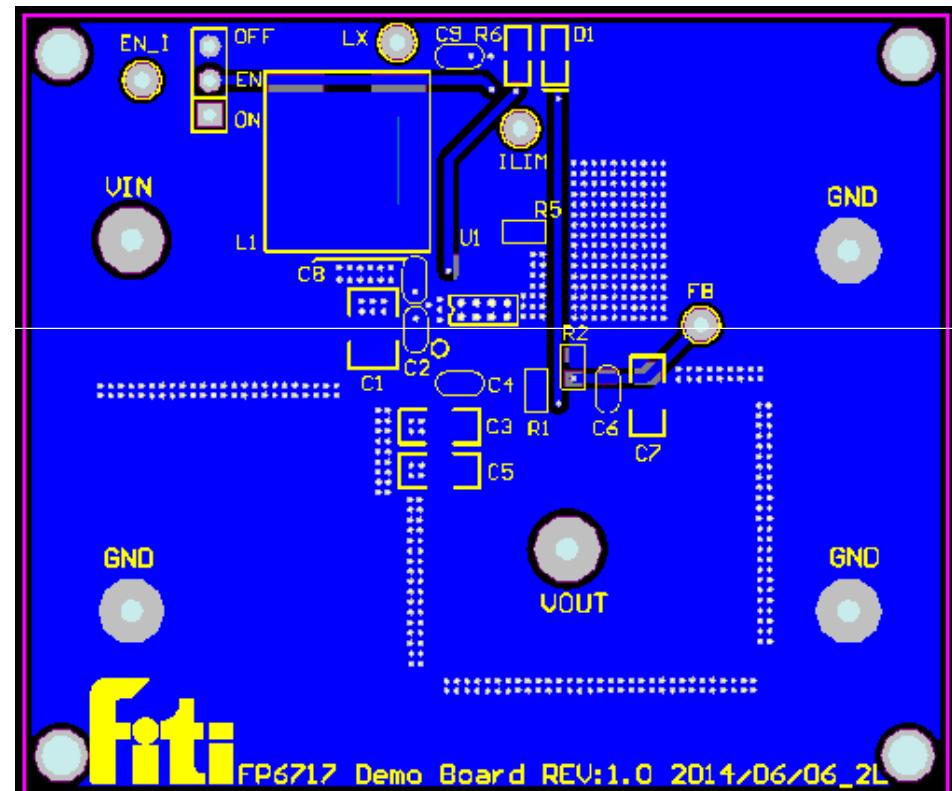
编号	元件类别	功能描述	附注
R1	贴片电阻	525KΩ 1/10W 1% 0603	
R2	贴片电阻	100KΩ 1/10W 1% 0603	
R4	贴片电阻	0805 2Ω 1/8W 5% 0805 (optional)	
R5	贴片电阻		
R6	贴片电阻	10KΩ 1/10W 1% 0603	
C1	贴片电容	MLCC 22uF±10% X5R 1206 type /16V	
C2	贴片电容	Ceramic Cap. 100nF 0603 type /50V	
C3	贴片电容	MLCC 22uF±10% X5R 1206 type /16V	
C4	贴片电容	Ceramic Cap. 100nF 0603 type /50V	
C5	贴片电容	MLCC 22uF±10% X5R 1206 type /16V	
C6	贴片电容	Ceramic Cap. 100nF 0603 type /50V	
C7	贴片电容	MLCC 22uF±10% X5R 1206 type /16V	
C8	贴片电容	Ceramic Cap. 1nF 0603 type /50V (optional)	
L1	电感	4.7uH 8A	
U1	IC	FP6717 (SOP-8 EP)	
	PCB	公板FP6717	

# FP6717 PCB 佈局指南

上视图



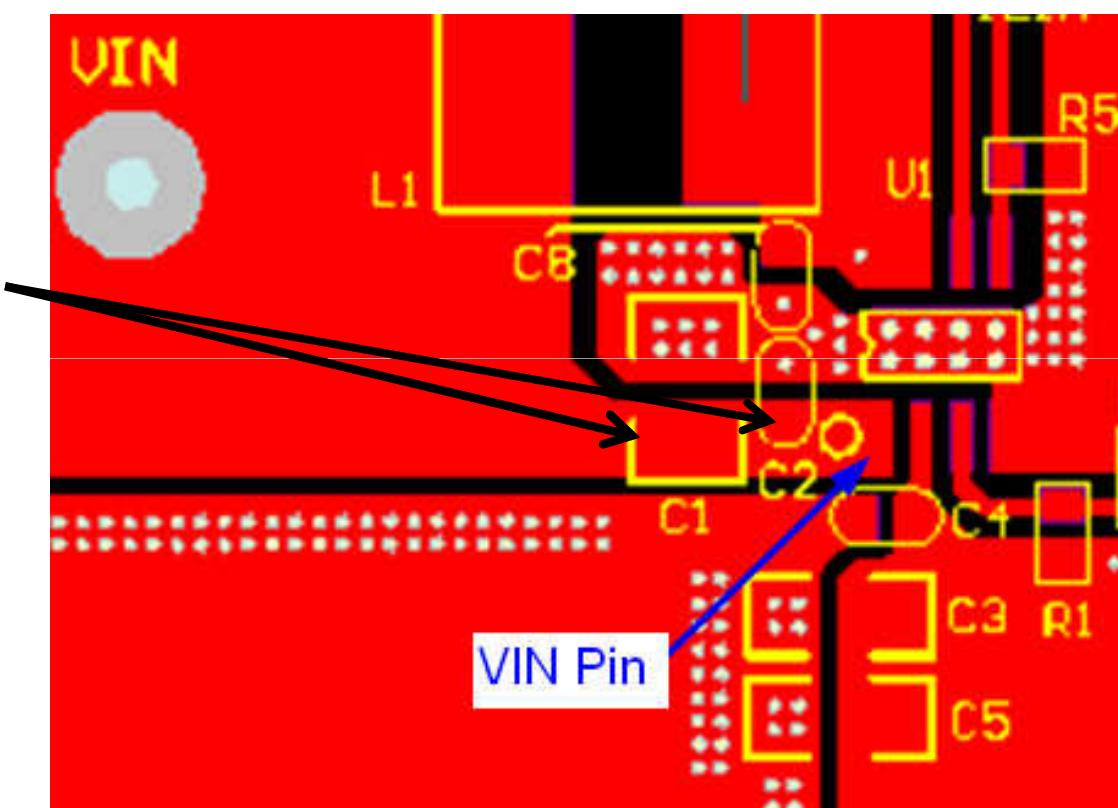
下视图



## 佈局指南一输入电容 $C_{IN}$ (一)

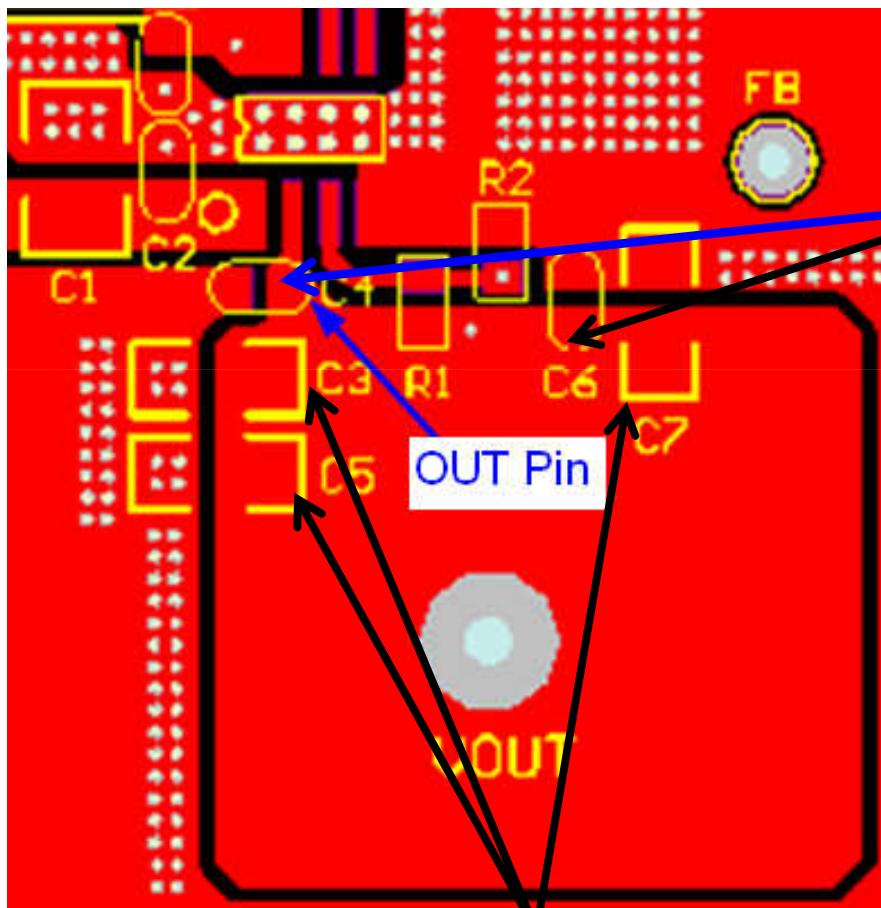
输入旁通电容必须靠近Vin 脚位 (IC脚位 1)，为了提升IC PSRR 抗无用信息能力。

如图所示， $C_2$ 旁通电容及 $C_1$ 稳压电容必须靠近IC Vin 脚位。



## 佈局指南一输出电容C<sub>OUT</sub>(二)

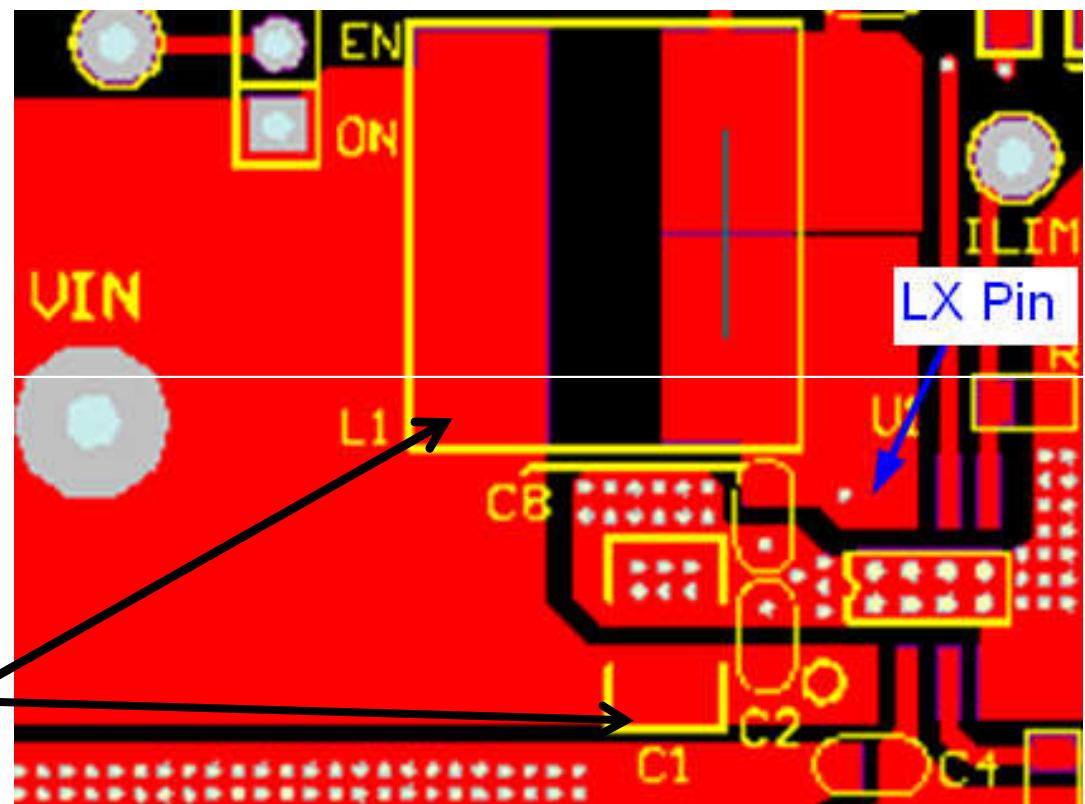
输出旁通电容必须靠近OUT 脚位 (IC脚位 2) ，可抑制高频无用信息。



如图所示，C4 / C6 旁通电容尽可能靠近IC 脚位。

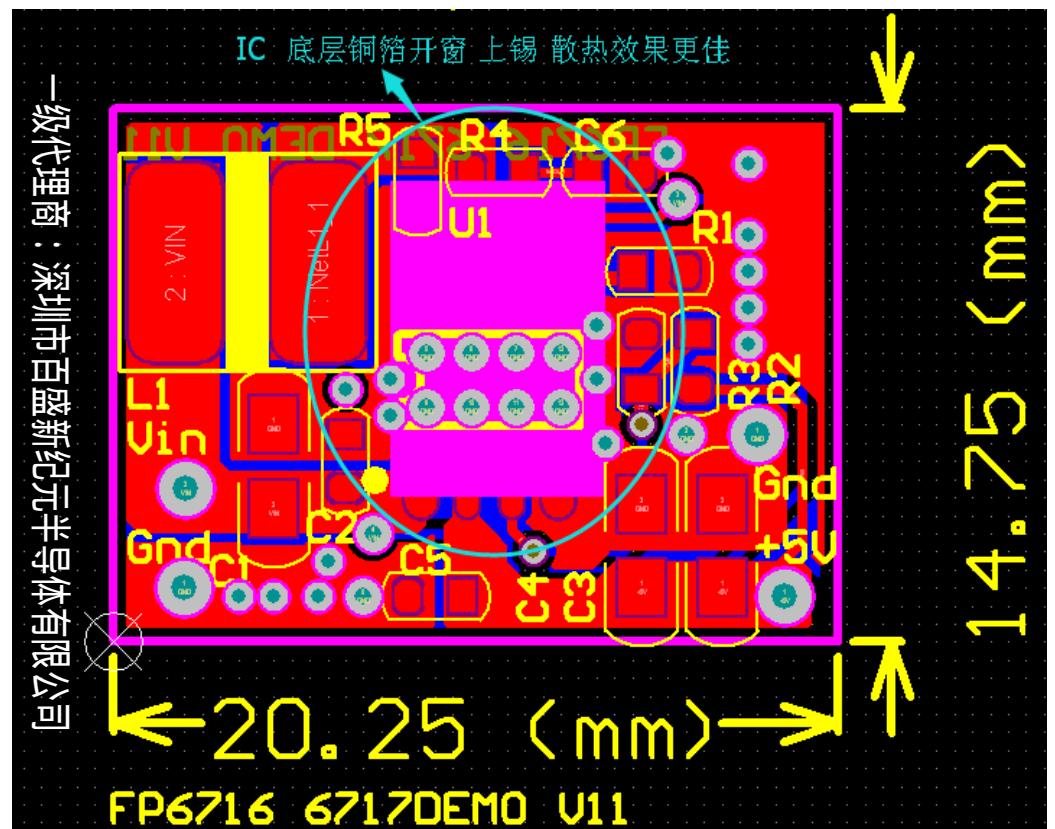
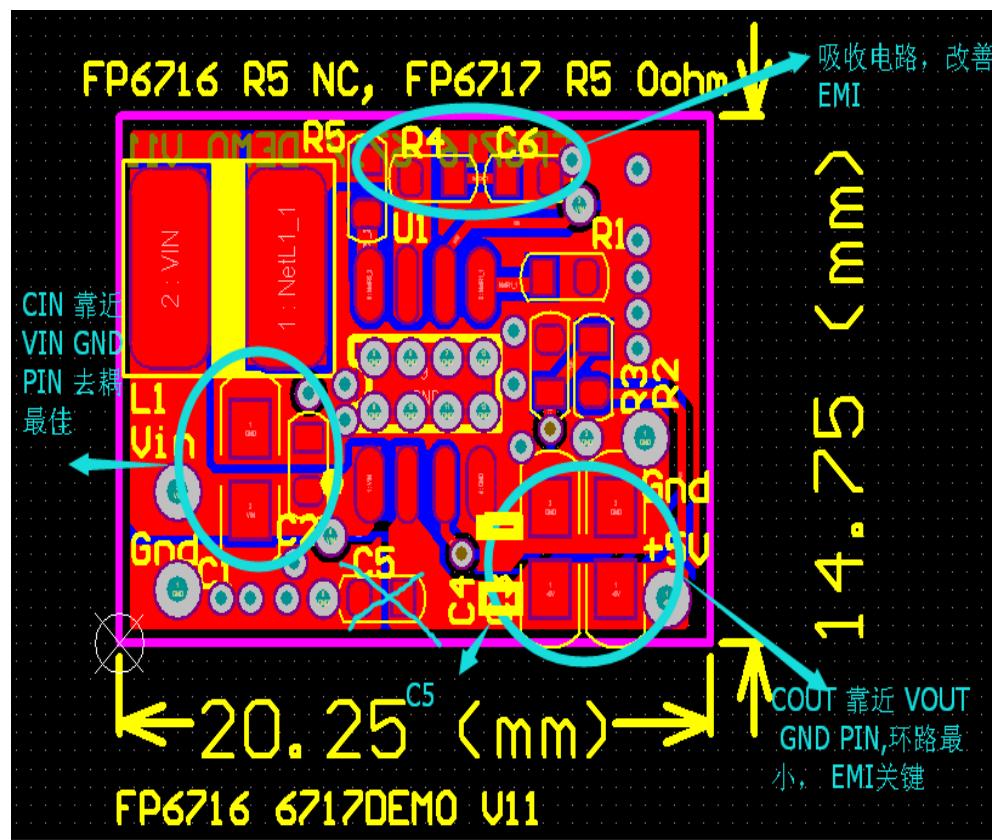
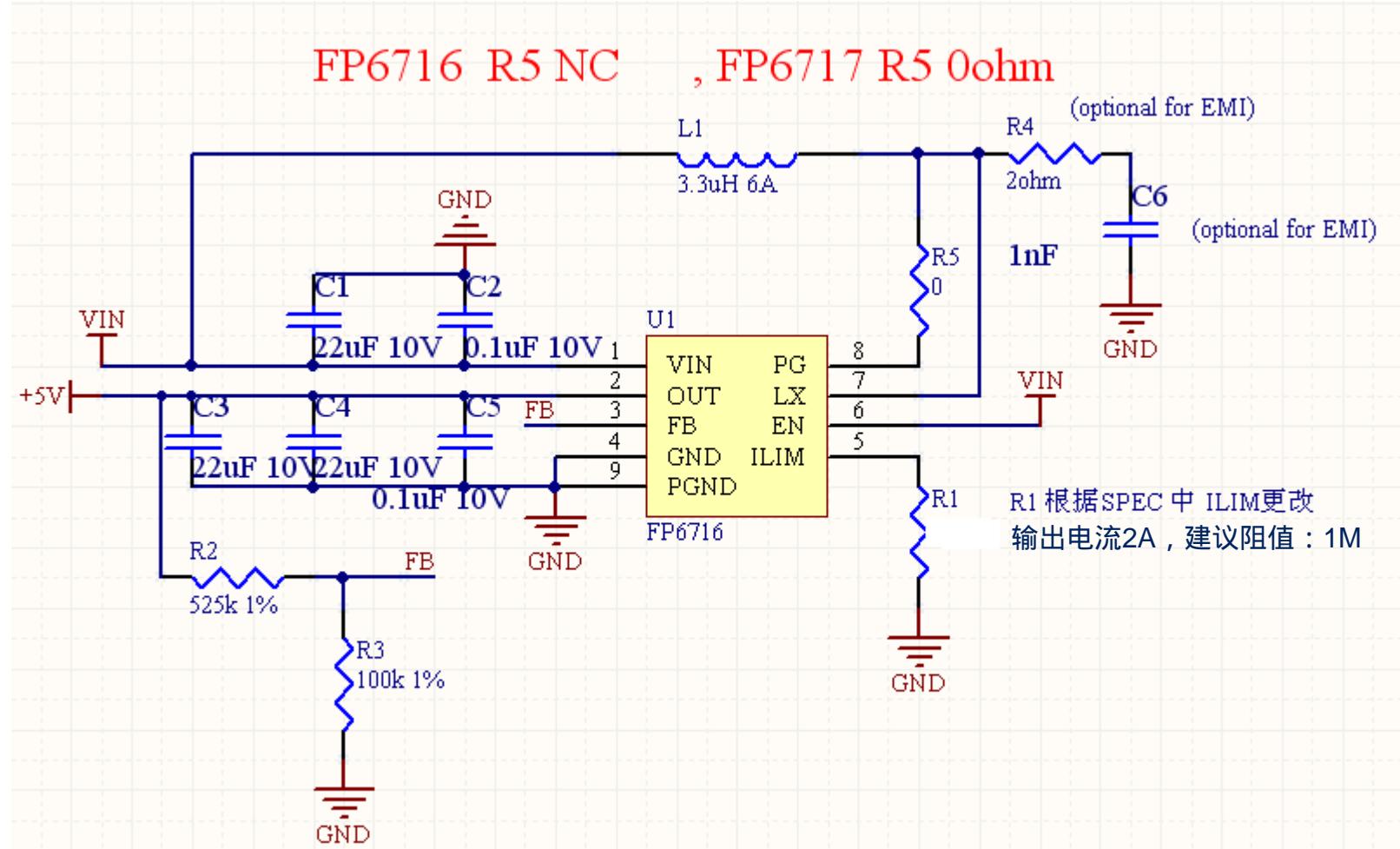
C3/C5/C7 稳压电容也尽可能靠近OUT 脚位。

电感L走线铜箔必须宽且短，尽可能与IC在同一板面，因为IC 内部MOS管依据占空比执行切换动作，则LX脚位有较高能量的切换干扰无用信息。



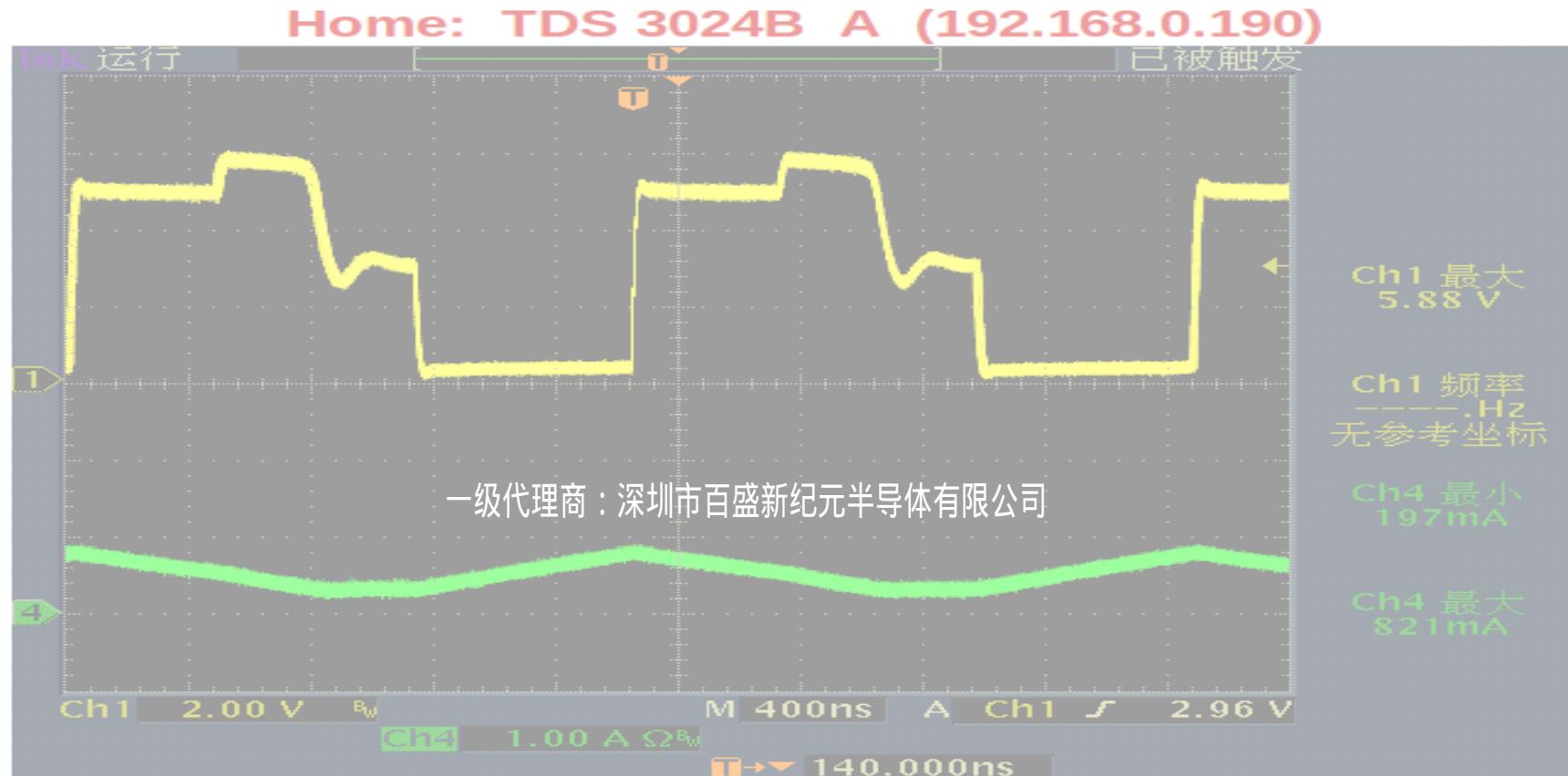
如图所示，电感L 的位置必须在 C1 电容之后，因为LX 脚位的切换无用信息能先被C1 电容抑制，避免直接干扰IC.

# 实际应用



## 注意事项

- 注意点：1、DCM 时，L电流未过零时，HS PMOS 切换至 body-diode，故出现如下波形，属正常波形。



- 注意点2：负载用纯电阻做带载插拔测试，输出电压正常。

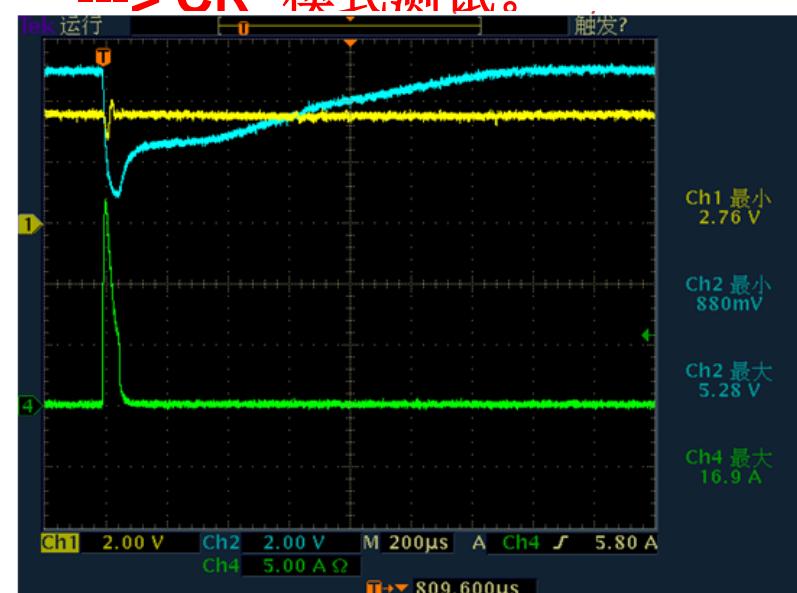
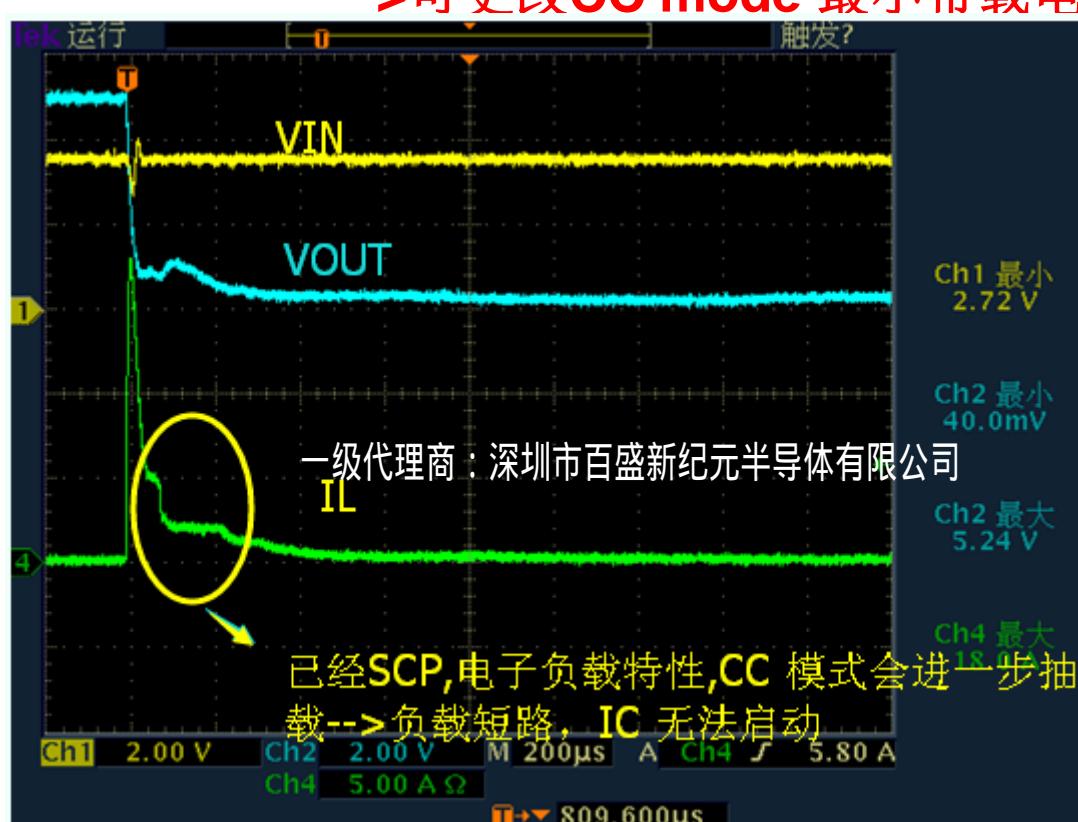
CONFIDENTIAL

电子负载 CC 模式带载插拔会触发SCP,至输出无电压。

---->可更改CC mode 最小带载电压，最小卸载电压（

$V_{off}$  3V ,通常电池充电IC 工作电压都在4V 以上。）

----> CR 模式测试。



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